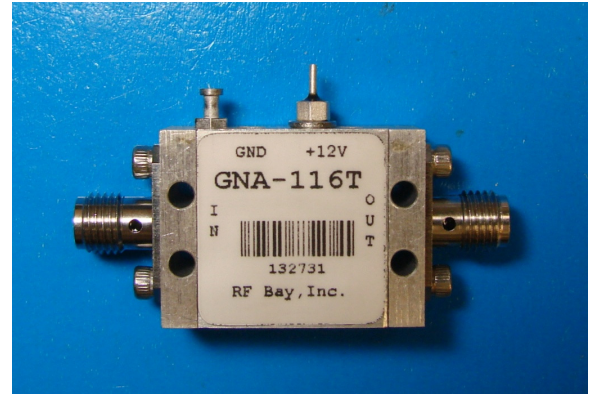


GNA Series**500 – 1000MHz Low Noise Amplifier****Features**

- Frequency Range:500 – 1000MHz
- Gain: 21dB
- P_{1dB}: +21dBm
- IP3: +36dBm
- Noise Figure: 0.4dB (typ.)
- DC Power: 12V @ 80mA
- SMA-female connectorized

Photo**Description**

GNA-116T is a high performance Microwave Low Noise (& Driver) Amplifier, with standard frequency range of 500MHz to 1000MHz.

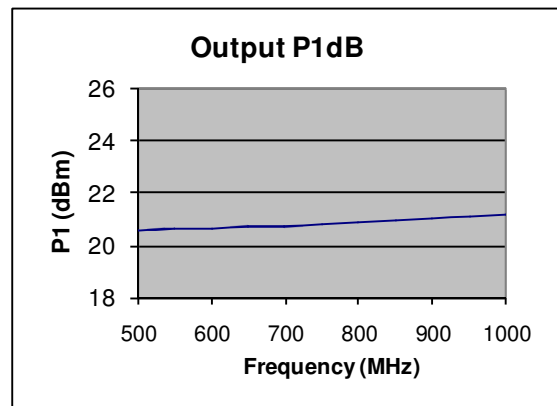
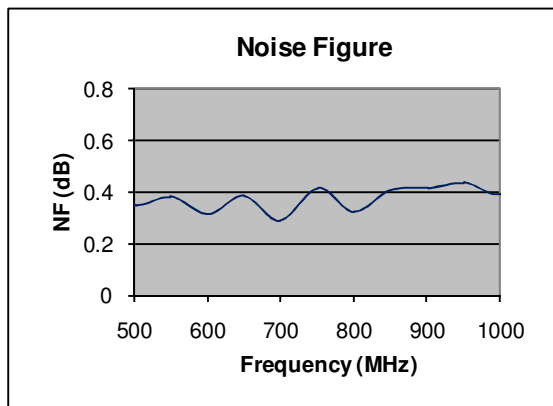
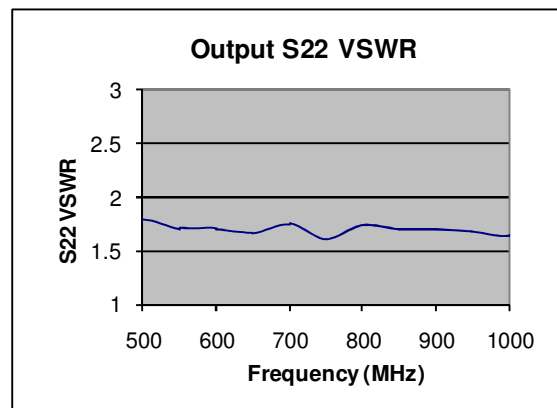
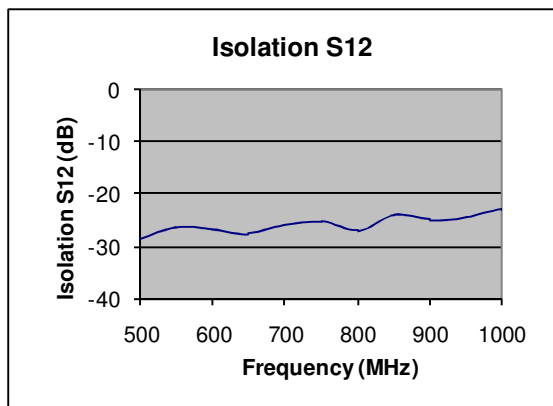
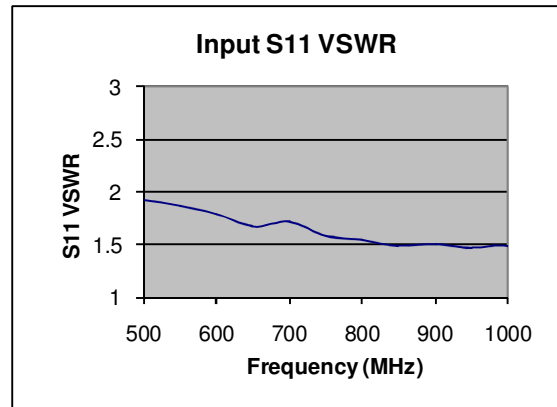
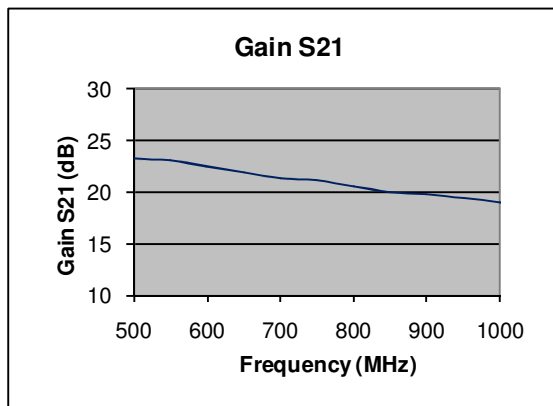
Electrical Specifications @+25 °C, Z_{in}=Z_{out}=50 Ohm, V_{supply} = +12VDC

Parameter	Unit	Minimum	Typical	Maximum
Frequency Range	MHz	500		1000
Gain (S ₂₁) f = 500MHz	dB		23	
f = 750MHz	dB		21	
f = 1000MHz	dB		19	
Gain Variation Over Temperature	dB/°C		0.02	0.03
Output Power P _{1dB}	dBm	+19	+21	
Saturated Output Power P _{Sat}	dBm		+23	
Output Third Order Intercept IP3	dBm	+32	+36	
Noise Figure @750MHz	dB		0.4	0.6
Reverse Isolation (S ₁₂) @750MHz	dB		-25	
VSWR-Input (S ₁₁)	ratio:1	2.0@500MHz	1.6@750MHz	1.5@1000MHz
VSWR-Output (S ₂₂)	(unitless)	1.8@500MHz	1.6@750MHz	1.7@1000MHz
DC Power Supply - voltage	V	9	12	15
DC Power Supply - current	mA		80	100
Operating Temperature	°C	-40		+85
Size (RF/DC feedthru's excluded)	Inch	1.00 (L) x 0.75 (W) x 0.45 (H)		
Weight	Oz	0.6 (17 grams)		

GNA Series

500 – 1000MHz Low Noise Amplifier

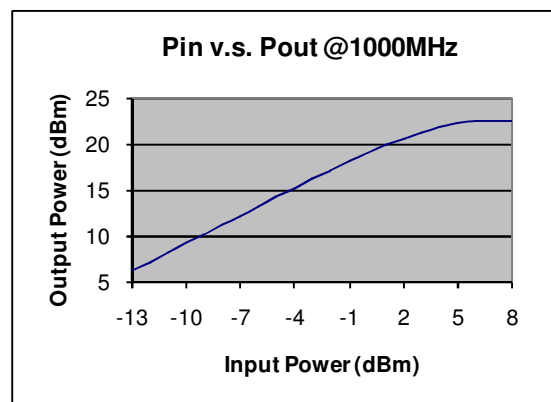
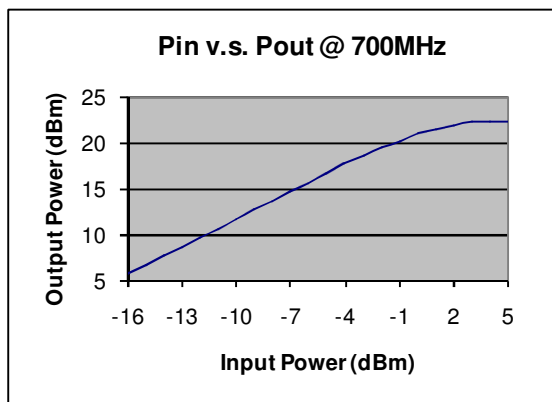
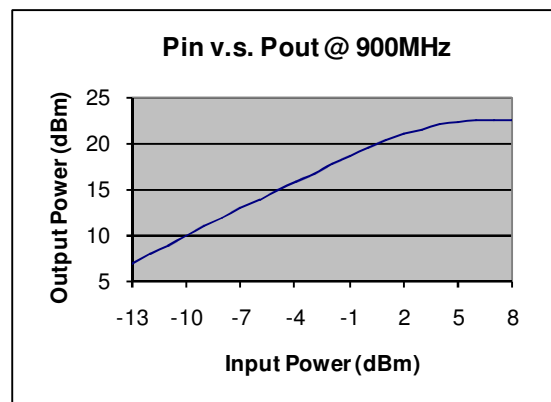
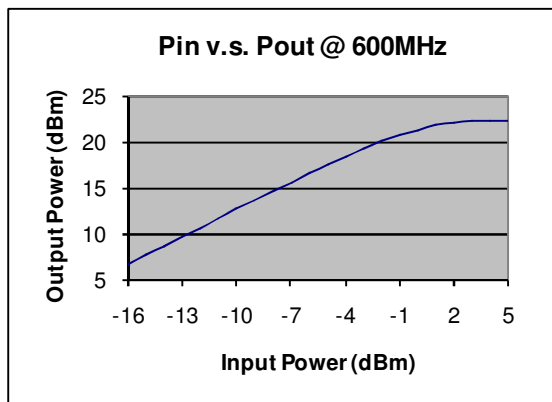
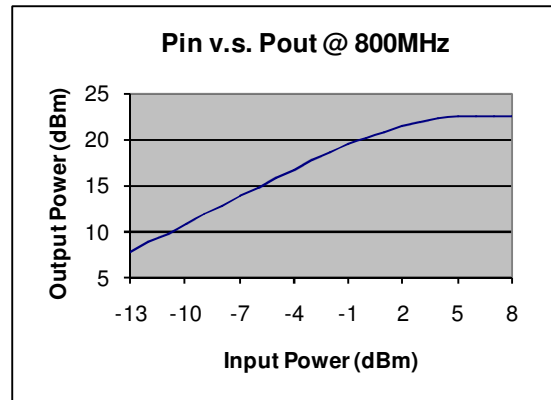
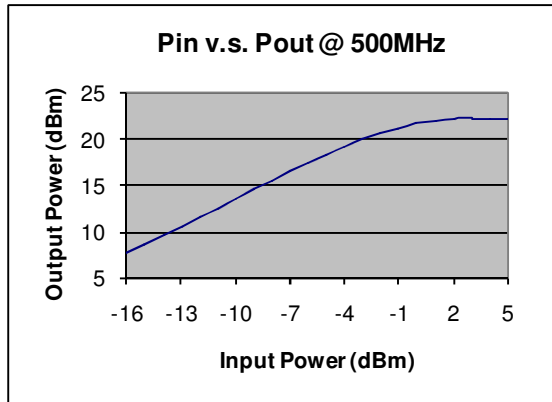
Typical Performance @+25 °C



GNA Series

500 – 1000MHz Low Noise Amplifier

Typical Performance @+25 °C



GNA Series

500 – 1000MHz Low Noise Amplifier

Absolute Maximum Ratings

Parameter	Absolute Maximum
RF Input Power	+22dBm
Supply Voltage (Survival)	+24V
Operating Temperature	-40 °C to +85 °C
Storage Temperature	-55 °C to +125 °C

Outline

